

RoHS

COMPLIANT

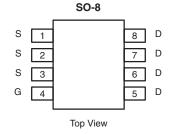
HALOGEN

Available

Vishay Siliconix

# N-Channel 25-V (D-S) MOSFET

PRODUCT SUMMARY						
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A) <sup>a</sup>	Q <sub>g</sub> (Typ.)			
25	0.004 at V <sub>GS</sub> = 10 V	28.6	29 nC			
25	0.0052 at $V_{GS}$ = 4.5 V	25.6	29110			

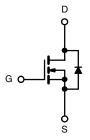


#### FEATURES

- Halogen-free According to IEC 61249-2-21
  Available
- TrenchFET<sup>®</sup> Power MOSFET
- 100 % R<sub>g</sub> Tested
- 100 % UIS Tested

#### **APPLICATIONS**

- Synchronous Buck-Low Side - Notebook, Game Console
- Synchronous Rectifier-POL



N-Channel MOSFET

Ordering Information: Si4654DY-T1-E3 (Lead (Pb)-free) Si4654DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V <sub>DS</sub>	25	V	
Gate-Source Voltage		V <sub>GS</sub>	± 16	v	
	T <sub>C</sub> = 25 °C		28.6		
Continuous Drain Current (T <sub>.1</sub> = 150 °C)	T <sub>C</sub> = 70 °C		23		
Continuous Drain Ourient (1) = 150°C)	T <sub>A</sub> = 25 °C		18.6 <sup>b, c</sup>		
	T <sub>A</sub> = 70 °C		14.9 <sup>b, c</sup>	Α	
Pulsed Drain Current		I <sub>DM</sub>	70	A	
Quality of the Data Data Divide Quart	T <sub>C</sub> = 25 °C	_	5.1		
Continuous Source-Drain Diode Current	T <sub>A</sub> = 25 °C	I <sub>S</sub>	2.2 <sup>b, c</sup>		
Single Pulse Avalanche Current	L = 0.1 mH	I <sub>AS</sub>	30		
valanche Energy L = 0.1 mH		E <sub>AS</sub>	45	mJ	
	T <sub>C</sub> = 25 °C		5.9		
Maximum Davier Disaination	T <sub>C</sub> = 70 °C		3.8	w	
Maximum Power Dissipation	T <sub>A</sub> = 25 °C	P <sub>D</sub>	2.5 <sup>b, c</sup>	VV	
	T <sub>A</sub> = 70 °C	1	1.6 <sup>b, c</sup>		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Typical	Maximum	Unit		
Maximum Junction-to-Ambient <sup>b, d</sup>	t ≤ 10 s	R <sub>thJA</sub>	37	50	°C/W		
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	17	21	0/11		

Notes:

a. Based on  $T_C = 25 \ ^{\circ}C$ .

b. Surface Mounted on 1" x 1" FR4 board.

c. t = 10 s.

d. Maximum under Steady State conditions is 85 °C/W.

# Si4654DY

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static	· · · · ·					
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 V, I_D = 250 \mu A$	25			V
V <sub>DS</sub> Temperature Coefficient	$\Delta V_{DS}/T_{J}$	/T <sub>J</sub> I <sub>D</sub> = 250 μA		26		m\//º(
V <sub>GS(th)</sub> Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	$I_D = 250 \mu A$		- 5.6		mV/°C
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \ \mu A$	1.0		2.5	V
Gate-Source Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 16 V$			± 100	nA
	I <sub>DSS</sub>	$V_{DS} = 25 V, V_{GS} = 0 V$			1	
Zero Gate Voltage Drain Current		$V_{DS} = 25 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 55 ^{\circ}\text{C}$			10	μΑ
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5$ V, $V_{GS} = 10$ V	30			Α
	5	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 15 A		0.0032	0.004	
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 10 A			0.0052	Ω
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 15 A		100		S
Dynamic <sup>b</sup>						
Input Capacitance	C <sub>iss</sub>			3770		
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0 V, f = 1 MHz		560		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			255		
		V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 10 V, I <sub>D</sub> = 10 A		63	100	
Total Gate Charge	$Q_g$		29	45	-	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 10 \text{ A}$		8.5		nC
Gate-Drain Charge	Q <sub>gd</sub>			7.2		
Gate Resistance	R <sub>g</sub>	f = 1 MHz		0.9	1.8	Ω
Turn-On Delay Time	t <sub>d(on)</sub>			30	50	-
Rise Time	t <sub>r</sub>	$V_{DD}$ = 15 V, $R_{L}$ = 3 $\Omega$		10	20	
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong 5 \text{ A}, V_{GEN} = 4.5 \text{ V}, R_g = 1 \Omega$		50	90	
Fall Time	t <sub>f</sub>			10	20	
Turn-On Delay Time	t <sub>d(on)</sub>			12	24	ns
Rise Time	t <sub>r</sub>	$V_{DD}$ = 15 V, $R_1$ = 3 $\Omega$		8	16	-
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong 5 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$		38	70	
Fall Time	t <sub>f</sub>			8	16	
Drain-Source Body Diode Characterist	ics					
Continuous Source-Drain Diode Current	۱ <sub>S</sub>	T <sub>C</sub> = 25 °C			5.1	•
Pulse Diode Forward Current <sup>a</sup>	I <sub>SM</sub>				70	A
Body Diode Voltage	V <sub>SD</sub>	I <sub>S</sub> = 3 A		0.73	1.1	V
Body Diode Reverse Recovery Time	t <sub>rr</sub>			32	60	ns
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>			26	55	nC
Reverse Recovery Fall Time	t <sub>a</sub>	$I_F = 5 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, \text{ T}_J = 25 ^\circ\text{C}$		16		
Reverse Recovery Rise Time t <sub>b</sub>				16		ns

Notes

a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %

b. Guaranteed by design, not subject to production testing.

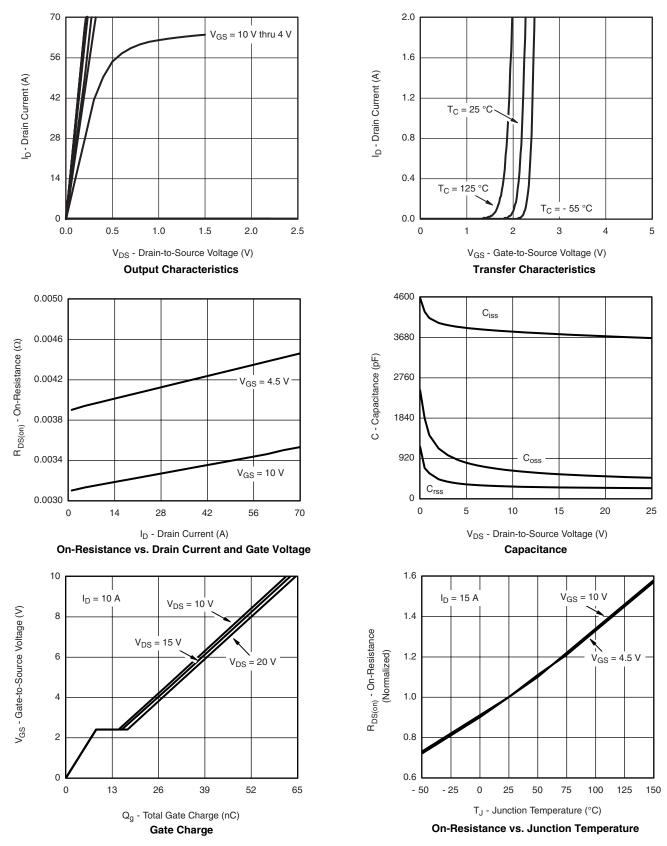
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



# Si4654DY

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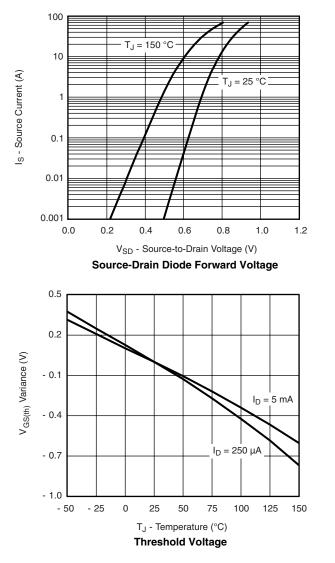


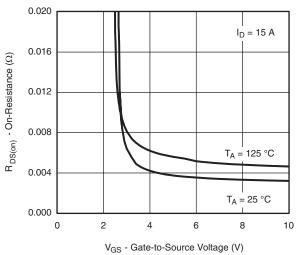
Document Number: 69813 S09-0138-Rev. C, 02-Feb-09

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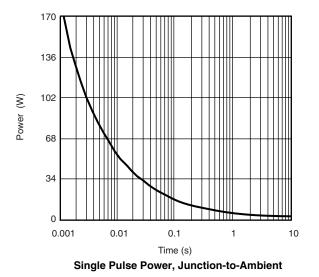


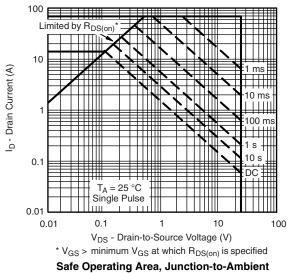
#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





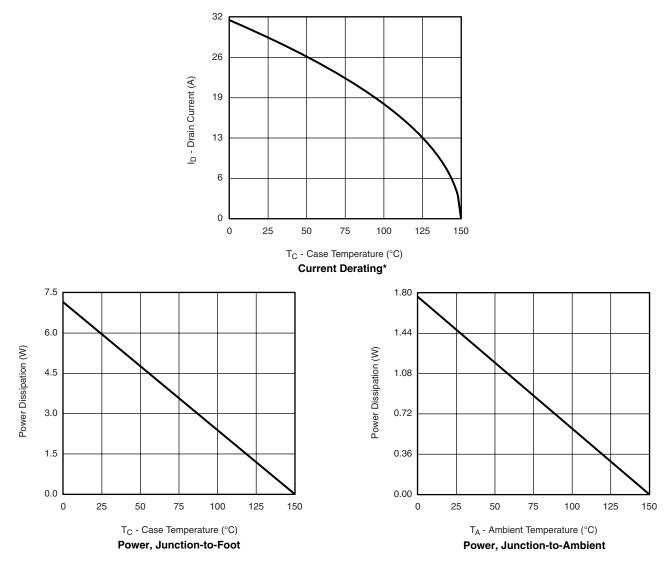
On-Resistance vs. Gate-to-Source Voltage







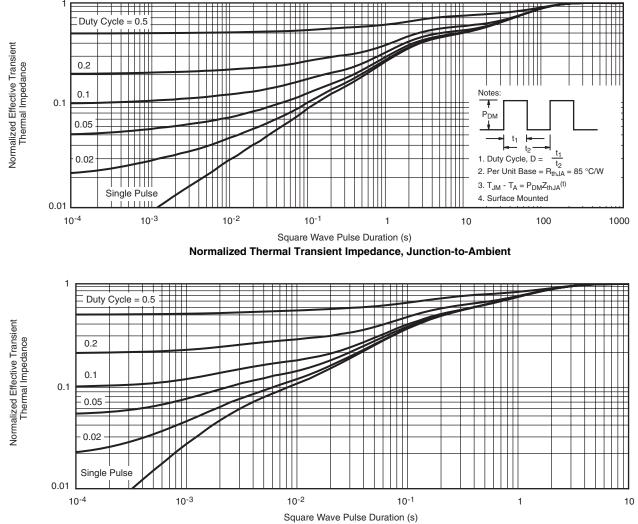
#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



\* The power dissipation  $P_D$  is based on  $T_{J(max)} = 150$  °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

### **Vishay Siliconix**

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <u>www.vishay.com/ppg?69813</u>.



# Package Information

Vishay Siliconix

# SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012





	MILLIM	IETERS	INCHES		
DIM	Min	Мах	Min	Max	
A	1.35	1.75	0.053	0.069	
A <sub>1</sub>	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
E	3.80	4.00	0.150	0.157	
е	1.27	BSC	0.050 BSC		
н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	
S	0.44	0.64	0.018	0.026	
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498					

# **Application Note 826**

Vishay Siliconix



**RECOMMENDED MINIMUM PADS FOR SO-8** 



Recommended Minimum Pads Dimensions in Inches/(mm)

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